

# **CGD944C**

# 870 MHz, 25 dB gain power doubler amplifier Rev. 4 — 25 June 2014

Product data sheet

#### 1. **Product profile**

### 1.1 General description

Hybrid amplifier module in a SOT115J package, operating at a supply voltage of 24 V (DC), employing Hetero Field Effect Transistor (HFET) GaAs dies.

#### 1.2 Features and benefits

- High output capability
- Excellent linearity
- Extremely low noise
- Excellent return loss properties
- Rugged construction
- Gold metallization ensures excellent reliability

### 1.3 Applications

CATV systems operating in the 40 MHz to 870 MHz frequency range

#### 1.4 Quick reference data

Table 1. **Quick reference data** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	f = 870 MHz	24	25	26	dB
I <sub>tot</sub>	total current	V <sub>B</sub> = 24 V [1]	-	450	-	mA

<sup>[1]</sup> Direct Current (DC).

#### 2. **Pinning information**

Table 2. **Pinning** 

Pin	Description	Simplified outline	Graphic symbol
1	input		<b>N</b> 1
2, 3	common	1 3 5 7 9	1 5 9
5	+V <sub>B</sub>		>
7, 8	common		2378
9	output		sym095



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### 3. Ordering information

Table 3. Ordering information

Type number	Package	je				
	Name	Description	Version			
CGD944C		rectangular single-ended package; aluminium flange; 2 vertical mounting holes; $2 \times 6-32$ UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads	SOT115J			

### 4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{B}$	supply voltage		-	30	V
V <sub>i(RF)</sub>	RF input voltage	single tone	-	75	dBmV
		132 channels flat	-	45	dBmV
T <sub>stg</sub>	storage temperature		-40	+100	°C
T <sub>mb</sub>	mounting base temperature		-20	+100	°C

### 5. Characteristics

Table 5. Characteristics

Bandwidth to 870 MHz;  $V_B = 24 \text{ V (DC)}$ ;  $T_{mb} = 35 \text{ }^{\circ}\text{C}$ ; unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Gp	power gain	f = 870 MHz		24	25	26	dB
SL <sub>sl</sub>	slope straight line	f = 40 MHz to 870 MHz	[1]	1	-	2	dB
FL	flatness of frequency response	f = 40 MHz to 870 MHz	[2]	-	0.5	-	dB
СТВ	composite triple beat	79 + 53 flat NTSC channels	[3]	-	-68	-66	dBc
		98 flat PAL channels	[4]	-	-66	-	dBc
CSO	composite second-order distortion	79 + 53 flat NTSC channels	[3]	-	-70	-67	dBc
		98 flat PAL channels	[4]	-	-66	-	dBc
Xmod	cross modulation	79 + 53 flat NTSC channels	[3]	-	-66	-58	dB
RLin	input return loss	f = 40 MHz to 80 MHz		20	-	-	dB
		f = 80 MHz to 160 MHz		19	-	-	dB
		f = 160 MHz to 320 MHz		18	-	-	dB
		f = 320 MHz to 640 MHz		18	-	-	dB
		f = 640 MHz to 870 MHz		18	-	-	dB
RL <sub>out</sub>	output return loss	f = 40 MHz to 80 MHz		20	-	-	dB
		f = 80 MHz to 160 MHz		19	-	-	dB
		f = 160 MHz to 320 MHz		18	-	-	dB
		f = 320 MHz to 640 MHz		18	-	-	dB
		f = 640 MHz to 870 MHz		18	-	-	dB

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### Table 5. Characteristics ...continued

Bandwidth to 870 MHz;  $V_B = 24 \text{ V (DC)}$ ;  $T_{mb} = 35 \text{ }^{\circ}\text{C}$ ; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
NF	noise figure	f = 50 MHz	-	3.5	5.0	dB
		f = 870 MHz	-	3.5	5.0	dB
I <sub>tot</sub>	total current	$V_B = 24 \text{ V}$ [5]	-	450	-	mΑ

- [1]  $G_p$  at 870 MHz minus  $G_p$  at 40 MHz.
- [2] flatness straight line (peak to valley).
- [3] 79 NTSC channels (5.25 MHz to 547.25 MHz, 48 dBmV output level) + 53 NTSC channels (553.25 MHz to 870 MHz, 38 dBmV output level).
- [4]  $V_0 = 48 \text{ dBmV}.$
- [5] Direct Current (DC).

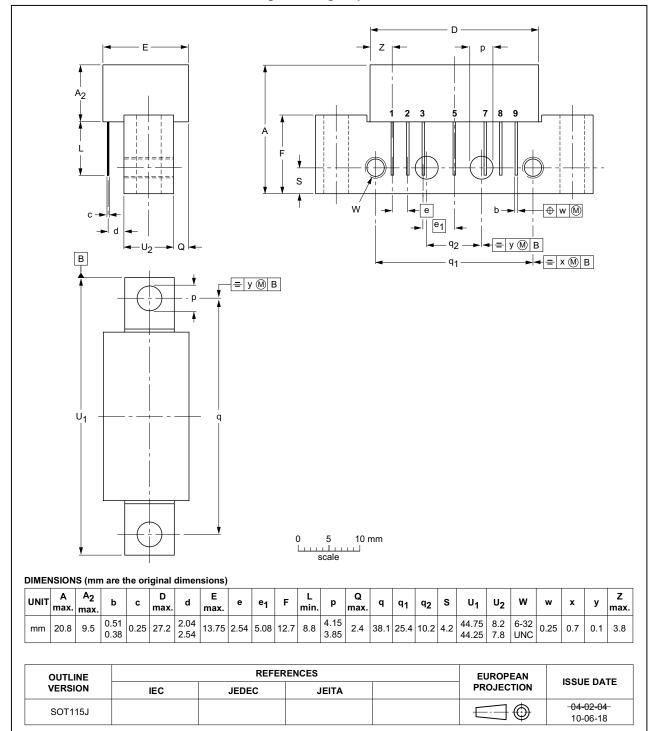
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### Package outline

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J



Package outline SOT115J Fig 1.

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### 7. Handling information

#### **CAUTION**



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

### 8. Abbreviations

Table 6. Abbreviations

Acronym	Description
CATV	Community Antenna TeleVision
DC	Direct Current
GaAs	Gallium-Arsenide
NTSC	National Television Standard Committee
PAL	Phase-Alternation Line
RF	Radio Frequency
UNC	UNified Coarse thread

## 9. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
CGD944C v.4	20140625	Product data sheet	-	CGD944C v.3	
Modifications:	• Table note 3 on page 3: 997.25 MHz has been changed to 870 MHz.				
	<ul> <li>Section 7 on page 5: The ESD warning has been moved here from the front page.</li> </ul>				
	Legal texts have been updated.				
CGD944C v.3	20100929	Product data sheet	-	CGD944C v.2	
CGD944C v.2	20091116	Product data sheet	-	CGD944C v.1	
CGD944C v.1	20070606	Product data sheet	-	-	

### 870 MHz, 25 dB gain power doubler amplifier

### 10. Legal information

#### 10.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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